

**LED DOT MATRIX**
**BL-M12X881**
**Features:**

- Ø 32.00mm (1.2") 1/3 dot matrix LED display.
- Ø Low current operation.
- Ø Excellent character appearance.
- Ø Easy mounting on P.C. Boards or sockets.
- Ø I.C. Compatible.
- Ø ROHS Compliance.


**Super Bright**
**Electrical-optical characteristics: (Ta=25 °C) (Test Condition: IF=20mA)**

Part No			Chip			VF Unit:V		Iv TYP.(mcd)
Row Cathode Column Anode	Row Anode Column Cathode	Emitted Color	Material	λp (nm)	Typ	Max		
BL-M12C881S-XX	BL-M12D881S-XX	Hi Red	GaAlAs/GaAs,SH	660	1.85	2.20	200	
BL-M12C881D-XX	BL-M12D881D-XX	Super Red	GaAlAs/GaAs,DH	660	1.85	2.20	320	
BL-M12C881UR-XX	BL-M12D881UR-XX	Ultra Red	GaAlAs/GaAs,DDH	660	1.85	2.20	400	
BL-M12C881E-XX	BL-M12D881E-XX	Orange	GaAsP/GaP	635	2.10	2.50	190	
BL-M12C881Y-XX	BL-M12D881Y-XX	Yellow	GaAsP/GaP	585	2.10	2.50	190	
BL-M12C881G-XX	BL-M12D881G-XX	Green	GaP/GaP	570	2.20	2.50	195	

**Ultra Bright**
**Electrical-optical characteristics: (Ta=25 °C) (Test Condition: IF=20mA)**

Part No			Chip			VF Unit:V		Iv TYP.(mcd)
Row Cathode Column Anode	Row Anode Column Cathode	Emitted Color	Material	λp (nm)	Typ	Max		
BL-M12C881UHR-XX	BL-M12D881UHR-XX	Ultra Red	AlGaInP	645	2.10	2.50	400	
BL-M12C881UE-XX	BL-M12D881UE-XX	Ultra Orange	AlGaInP	630	2.10	2.50	235	
BL-M12C881YO-XX	BL-M12D881YO-XX	Ultra Amber	AlGaInP	619	2.10	2.50	235	
BL-M12C881UY-XX	BL-M12D881UY-XX	Ultra Yellow	AlGaInP	590	2.10	2.50	235	
BL-M12C881UG-XX	BL-M12D881UG-XX	Ultra Green	AlGaInP	574	2.20	2.50	250	
BL-M12C881PG-XX	BL-M12D881PG-XX	Ultra Pure Green	InGaN	525	3.80	4.50	270	
BL-M12C881B-XX	BL-M12D881B-XX	Ultra Blue	InGaN	470	2.70	4.20	180	
BL-M12C881W-XX	BL-M12D881W-XX	Ultra White	InGaN	/	2.70	4.20	300	

--XX: Surface / Lens color :

Number	0	1	2	3	4	5
Ref Surface Color	White	Black	Gray	Red	Green	
Epoxy Color	Water clear	White diffused	Red Diffused	Green Diffused	Yellow Diffused	

**LED DOT MATRIX**
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**Absolute maximum ratings (Ta=25°C)**

Parameter	S	D	UR	E	Y	G	Unit
Forward Current $I_F$	25	25	25	25	25	30	mA
Power Dissipation $P_d$	60	60	60	60	60	65	mW
Reverse Voltage $V_R$	5	5	5	5	5	5	V
Peak Forward Current $I_{PF}$ (Duty 1/10 @1KHZ)	150	150	150	150	150	150	mA
Operation Temperature $T_{OPR}$	-40 to +80						°C
Storage Temperature $T_{STG}$	-40 to +85						°C
Lead Soldering Temperature $T_{SOL}$	Max.260±5°C for 3 sec Max. (1.6mm from the base of the epoxy bulb)						°C

**Absolute maximum ratings (Ta=25°C)**

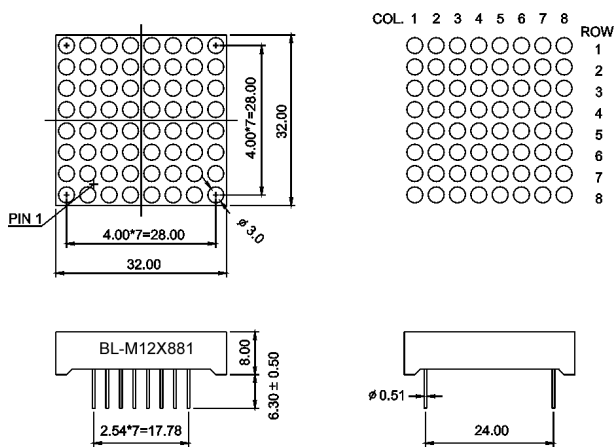
Parameter	UHR	UE	YO	UY	UG	PG	B	W	Unit
Forward Current $I_F$	30	30	30	30	30	30	30	30	mA
Power Dissipation $P_d$	75	65	65	65	75	110	120	120	mW
Reverse Voltage $V_R$	5	5	5	5	5	5	5	5	V
Peak Forward Current $I_{PF}$ (Duty 1/10 @1KHZ)	150	150	150	150	150	150	100	100	mA
Operation Temperature $T_{OPR}$	-40 to +80								°C
Storage Temperature $T_{STG}$	-40 to +85								°C
Lead Soldering Temperature $T_{SOL}$	Max.260±5°C for 3 sec Max. (1.6mm from the base of the epoxy bulb)								°C

LED DOT MATRIX

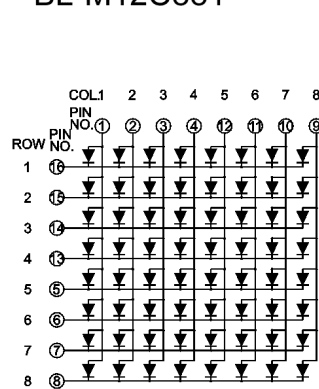
BL-M12X881

Package configuration & Internal circuit diagram

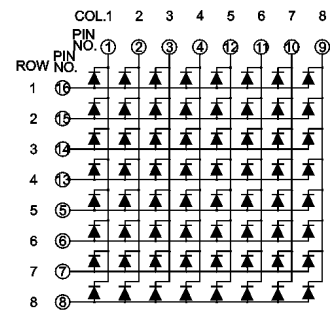
BL-M12X881 Series



BL-M12C881



BL-M12D881



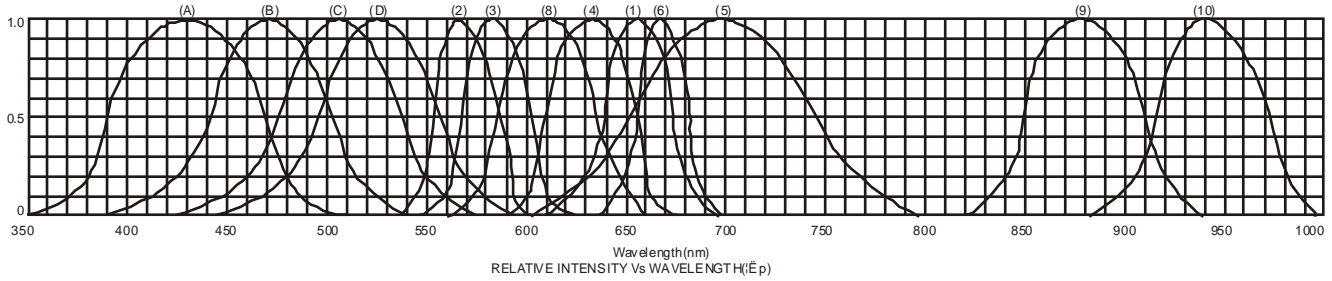
Notes:

1. All dimensions are in millimeters (inches)
2. Tolerance is  $\pm 0.25(0.01)$  unless otherwise noted.
3. Specifications are subject to change without notice.

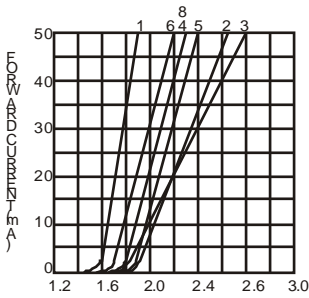
**LED DOT MATRIX**

**BL-M12X881**

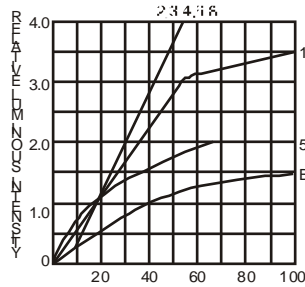
**Typical electrical-optical characteristics curves:**



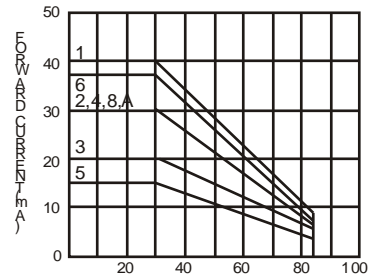
- (1) - GaAsP/GaAs 655nm/Red
- (2) - GaP 570nm/Yellow Green
- (3) - GaAsP/GaP 585nm/Yellow
- (4) - GaAsP/GaP 635nm/Orange & Hi-Eff Red
- (5) - GaP 700nm/Bright Red
- (6) - GaAlAs/GaAs 660nm/Super Red
- (8) - GaAsP/GaP 610nm/Super Red
- (9) - GaAlAs 880nm
- (10) - GaAs/GaAs & GaAlAs/GaAs 940nm
- (A) - GaN/SiC 430nm/Blue
- (B) - InGaN/SiC 470nm/Blue
- (C) - InGaN/SiC 505nm/Ultra Green
- (D) - InGaAlSiC 525nm/Ultra Green



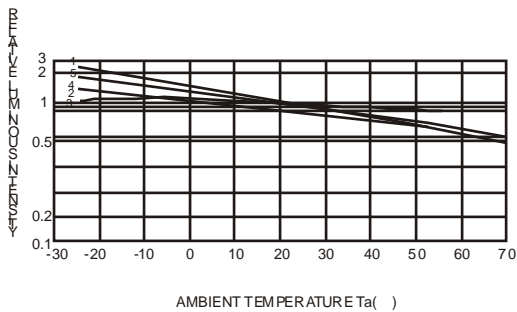
FORWARD VOLTAGE (Vf)  
FORWARD CURRENT VS.  
FORWARD VOLTAGE



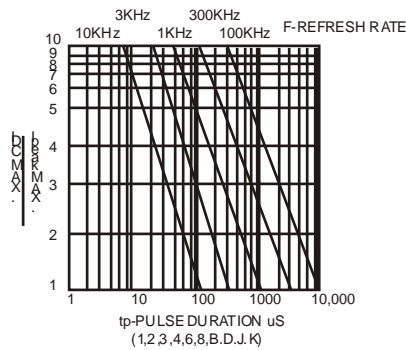
FORWARD CURRENT (mA)  
RELATIVE LUMINOUS  
INTENSITY VS. FORWARD  
CURRENT



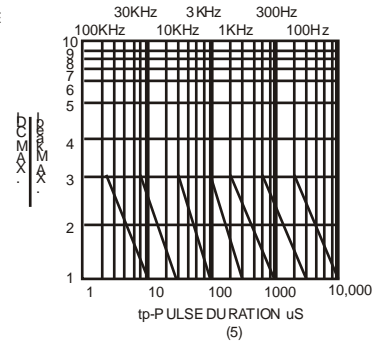
AMBIENT TEMPERATURE Ta ( °C )  
FORWARD CURRENT VS. AMBIENT  
TEMPERATURE



AMBIENT TEMPERATURE Ta ( °C )



tp-PULSE DURATION  $\mu$ s  
(1,2,3,4,6,8,B,D,J,K)



(5)

NOTE: 25 free air temperature unless otherwise specified